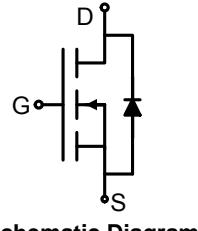


DESCRIPTION

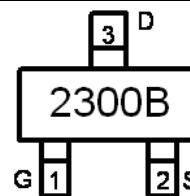
The SSF2300B uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a Battery protection or in other Switching application.



Schematic Diagram

FEATURES

- $V_{DS} = 20V, I_D = 4.5A$
- $R_{DS(ON)} < 115m\Omega @ V_{GS}=2.5V$
- $R_{DS(ON)} < 60m\Omega @ V_{GS}=4.5V$
- High Power and Current Handling Capability
- Lead Free



Marking and Pin Assignment

APPLICATIONS

- Battery Protection
- Load Switch
- Power Management



SOT-23-3L Top View

PACKAGE MARKING AND ORDERING INFORMATION

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2300B	SSF2300B	SOT-23-3L	Ø180mm	8 mm	3000 units

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Drain Current-Continuous@ Current-Pulsed (Note 1)	I_D	4.5	A
	I_{DM}	16	A
Maximum Power Dissipation	P_D	1.2	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	140	°C/W
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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	20			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=20\text{V}, V_{\text{GS}}=0\text{V}$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}=\pm 10\text{V}, V_{\text{DS}}=0\text{V}$			± 100	nA
ON CHARACTERISTICS (Note 3)						
Gate Threshold Voltage	$V_{\text{GS(th)}}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	0.65	0.95	1.2	V
Drain-Source On-State Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}}=2.5\text{V}, I_{\text{D}}=3.1\text{A}$		70	115	$\text{m}\Omega$
		$V_{\text{GS}}=4.5\text{V}, I_{\text{D}}=3.6\text{A}$		45	60	$\text{m}\Omega$
Forward Transconductance	g_{FS}	$V_{\text{DS}}=10\text{V}, I_{\text{D}}=4.5\text{A}$		8		S
DYNAMIC CHARACTERISTICS (Note 4)						
Input Capacitance	C_{iss}	$V_{\text{DS}}=10\text{V}, V_{\text{GS}}=0\text{V}, F=1.0\text{MHz}$		500		PF
Output Capacitance	C_{oss}			250		PF
Reverse Transfer Capacitance	C_{rss}			90		PF
SWITCHING CHARACTERISTICS (Note 4)						
Turn-on Delay Time	$t_{\text{d(on)}}$	$V_{\text{DD}}=10\text{V}, R_{\text{L}} = 2.8 \Omega, V_{\text{GS}}=4.5\text{V}, R_{\text{GEN}}=6\Omega, I_{\text{D}}=3.6\text{A},$		7		nS
Turn-on Rise Time	t_{r}			55		nS
Turn-Off Delay Time	$t_{\text{d(off)}}$			16		nS
Turn-Off Fall Time	t_{f}			10		nS
Total Gate Charge	Q_{g}	$V_{\text{DS}}=10\text{V}, I_{\text{D}}=4.2\text{A}, V_{\text{GS}}=4.5\text{V}$		10		nC
Gate-Source Charge	Q_{gs}			2.3		nC
Gate-Drain Charge	Q_{gd}			2.9		nC
DRAIN-SOURCE DIODE CHARACTERISTICS						
Diode Forward Voltage (Note 3)	V_{SD}	$V_{\text{GS}}=0\text{V}, I_{\text{S}}=1.3\text{A}$			1.2	V

NOTES:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production testing.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

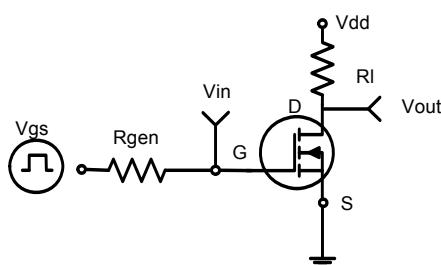


Figure 1: Switching Test Circuit

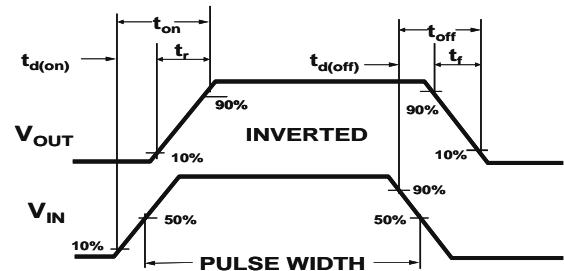
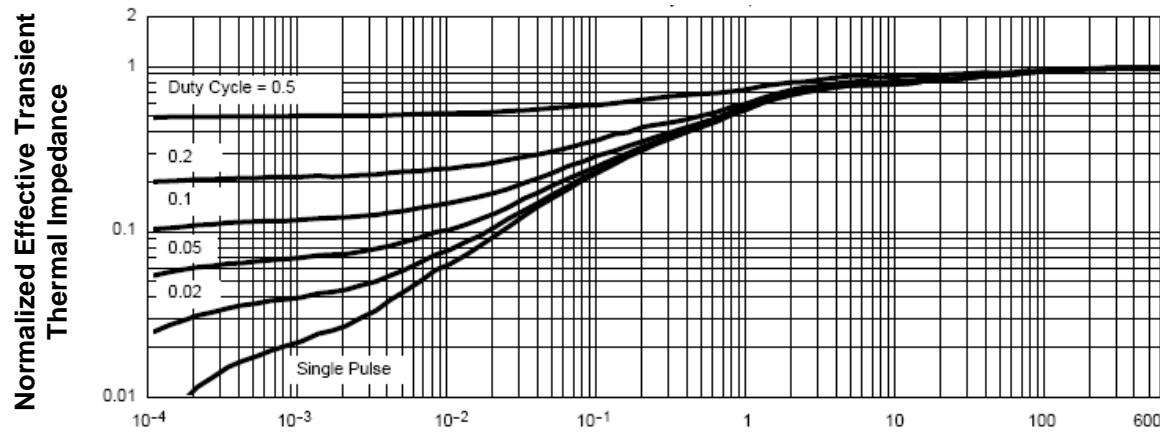
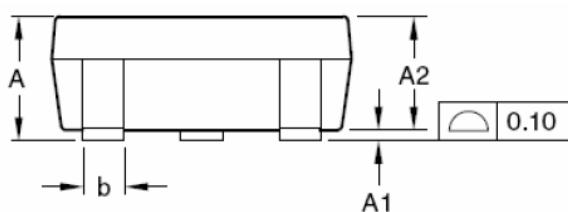
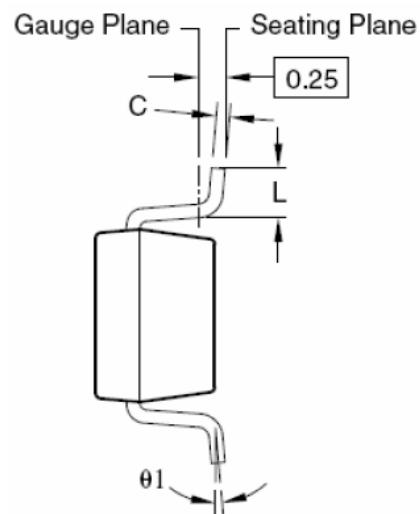
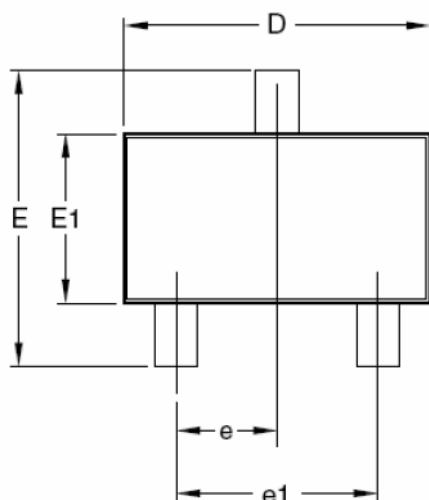


Figure 2: Switching Waveforms

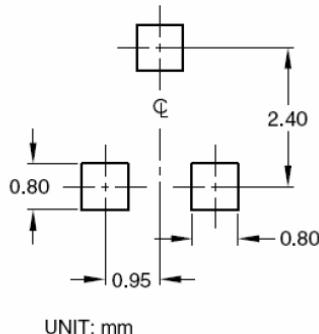


Square Wave Pulse Duration(sec)
 Figure 3: Normalized Maximum Transient Thermal Impedance

SOT-23-3L PACKAGE INFORMATION



RECOMMENDED LAND PATTERN



Dimensions in millimeters

Symbols	Min.	Nom.	Max.
A	0.90	—	1.25
A1	0.00	—	0.13
A2	0.70	1.00	1.15
b	0.30	0.40	0.50
C	0.08	0.13	0.20
D	2.80	2.90	3.10
E	2.60	2.80	3.00
E1	1.40	1.60	1.80
e	0.95 BSC		
e1	1.90 BSC		
L	0.30	—	0.60
theta1	0°	5°	8°

Dimensions in inches

Symbols	Min.	Nom.	Max.
A	0.035	—	0.049
A1	0.000	—	0.005
A2	0.028	0.039	0.045
b	0.012	0.016	0.020
C	0.003	0.005	0.008
D	0.110	0.114	0.122
E	0.102	0.110	0.118
E1	0.055	0.063	0.071
e	0.037 BSC		
e1	0.075 BSC		
L	0.012	—	0.024
theta1	0°	5°	8°

NOTES:

1. Tolerance $\pm 0.10\text{mm}$ (4 mil) unless otherwise specified
2. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
3. Dimension L is measured in gauge plane.
4. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.